8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Rev. 9 — 28 February 2017

Product data sheet

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1 General description

The 74HC595; 74HCT595 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (DS) and a serial output (Q7S) to enable cascading and an asynchronous reset $\overline{\text{MR}}$ input. A LOW on $\overline{\text{MR}}$ will reset the shift register. Data is shifted on the LOW-to-HIGH transitions of the SHCP input. The data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register. Data in the storage register appears at the output whenever the output enable input ($\overline{\text{OE}}$) is LOW. A HIGH on $\overline{\text{OE}}$ causes the outputs to assume a high-impedance OFF-state. Operation of the $\overline{\text{OE}}$ input does not affect the state of the registers. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2 Features and benefits

- 8-bit serial input
- 8-bit serial or parallel output
- Storage register with 3-state outputs
- · Shift register with direct clear
- 100 MHz (typical) shift out frequency
- Complies with JEDEC standard no. 7A
- Input levels:
 - For 74HC595: CMOS level
 - For 74HCT595: TTL level
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

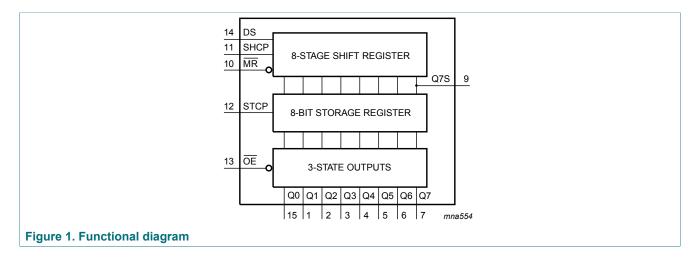
3 Applications

- Serial-to-parallel data conversion
- Remote control holding register

4 Ordering information

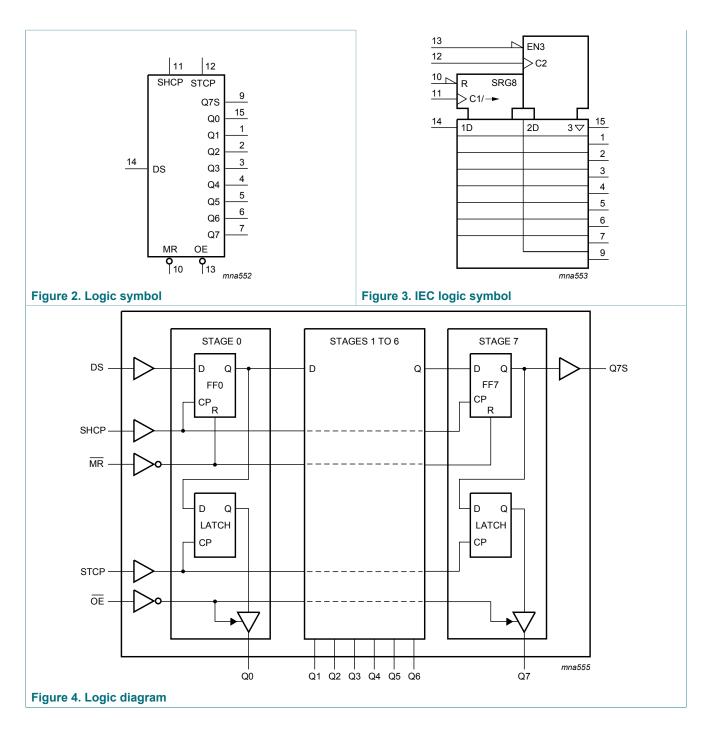
Type number	Package									
	Temperature range	Name	Description	Version						
74HC595D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1						
74HCT595D			body width 3.9 mm							
74HC595DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1						
74HCT595DB			body width 5.3 mm							
74HC595PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1						
74HCT595PW			body width 4.4 mm							
74HC595BQ	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1						
74HCT595BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm							

5 Functional diagram



74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

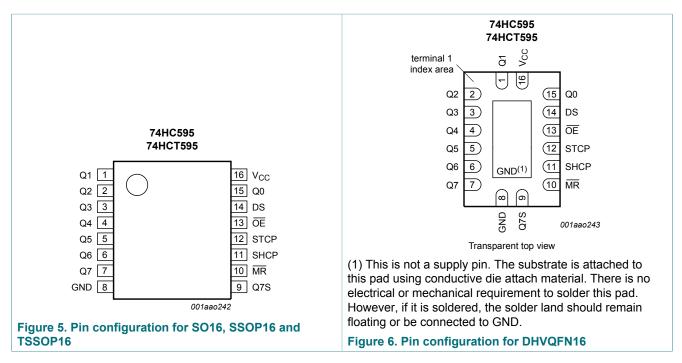


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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

6 Pinning information

6.1 Pinning



6.2 Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
MR	10	master reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
OE	13	output enable input (active LOW)
DS	14	serial data input
Q0	15	parallel data output 0
V _{cc}	16	supply voltage

7 Functional description

Table 3.	Functio	n tabl	e ^[1]				
Contro	bl			Input	Outpu	ıt	Function
SHCP	STCP	OE	MR	DS	Q7S	Qn	
Х	Х	L	L	Х	L	NC	a LOW-level on $\overline{\text{MR}}$ only affects the shift registers
Х	1	L	L	Х	L	L	empty shift register loaded into storage register
Х	Х	н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state
1	X	L	Н	Н	Q6S	NC	logic HIGH-level shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S).
х	↑	L	Η	х	NC	QnS	contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages
1	1	L	Η	X	Q6S	QnS	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages

[1] H = HIGH voltage state;

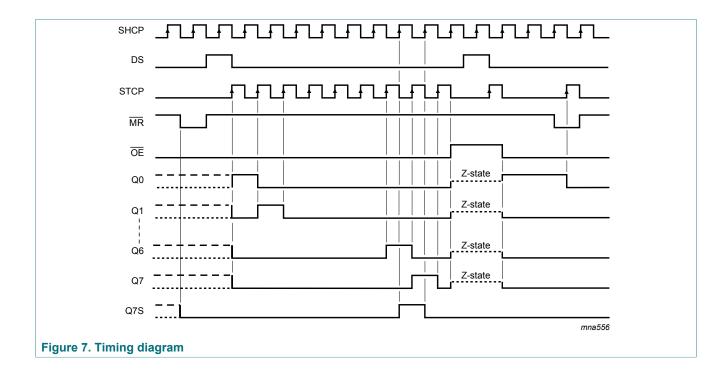
L = LOW voltage state;

 \uparrow = LOW-to-HIGH transition;

X = don't care;

NC = no change;

Z = high-impedance OFF-state.



Limiting values 8

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V)			
		pin Q7S	-	±25	mA
		pins Qn	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16 package [1]	-	500	mW
		SSOP16 package ^[2]	-	500	mW
		TSSOP16 package ^[2]	-	500	mW
		DHVQFN16 package [3]	-	500	mW

[1]

For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C. For DHVQFN16 package: P_{tot} derates linearly with 4.5 mW/K above 60 °C. [2]

[3]

Recommended operating conditions 9

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	-	74HC59	5	74HCT595			Unit
			Min	Тур	Мах	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
Δt/ΔV	input transition rise and	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

10 Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Мах	Min	Мах	
74HC595								
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	all outputs						
		I_{O} = -20 µA; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	V
		I_{O} = -20 µA; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	V
		Q7S output						
		I _O = -4 mA; V _{CC} = 4.5 V	3.84	4.32	-	3.7	-	V
		$I_{\rm O}$ = -5.2 mA; $V_{\rm CC}$ = 6.0 V	5.34	5.81	-	5.2	-	V
		Qn bus driver outputs						
		I _O = -6 mA; V _{CC} = 4.5 V	3.84	4.32	-	3.7	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	5.81	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	all outputs						
		I_0 = 20 µA; V_{CC} = 2.0 V	-	0	0.1	-	0.1	V
		I_{O} = 20 µA; V_{CC} = 4.5 V	-	0	0.1	-	0.1	V
		I_{O} = 20 µA; V_{CC} = 6.0 V	-	0	0.1	-	0.1	V
		Q7S output						
		I _O = 4 mA; V _{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
		Qn bus driver outputs						
		I _O = 6 mA; V _{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	-	±1.0	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 6.0 \text{ V};$ $V_{O} = V_{CC} \text{ or } \text{GND}$	-	-	±5.0	-	±10	μA

74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	• +125 °C	Unit
			Min	Тур	Мах	Min	Max	_
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	80	-	160	μA
Cı	input capacitance		-	3.5	-	-	-	pF
74HCT59	5	1		1		1		
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V _{OH}	HIGH-level	V_{I} = V_{IH} or V_{IL} ; V_{CC} = 4.5 V						
	output voltage	all outputs						
		I _O = -20 μA	4.4	4.5	-	4.4	-	V
		Q7S output						
		I _O = -4 mA	3.84	4.32	-	3.7	-	V
		Qn bus driver outputs						
		I _O = -6 mA	3.7	4.32	-	3.7	-	V
V _{OL}	LOW-level	V_{I} = V_{IH} or V_{IL} ; V_{CC} = 4.5 V						
	output voltage	all outputs						
		I _O = 20 μA	-	0	0.1	-	0.1	V
		Q7S output						
		I _O = 4.0 mA	-	0.15	0.33	-	0.4	V
		Qn bus driver outputs						
		I _O = 6.0 mA	-	0.16	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	-	±1.0	μA
I _{OZ}	OFF-state output current		-	-	±5.0	-	±10	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	-	160	μA
ΔI _{CC}	additional supply current	per input pin; other inputs at V_{CC} or GND; $I_0 = 0 A$; $V_1 = V_{CC} - 2.1 V$; $V_{CC} = 4.5 V$ to 5.5 V						
		pins $\overline{\text{MR}}$, SHCP, STCP, $\overline{\text{OE}}$	-	150	675	-	735	μA
		pin DS	-	25	113	-	123	μA
Cı	input capacitance		-	3.5	-	-	-	pF

11 Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions			25 °C			°C to 5 °C		°C to 5 °C	Unit
			Ν	/lin	Тур ^[1]	Max	Min	Max	Min	Мах	
74HC595							1				_
t _{pd}	propagation	SHCP to Q7S; see Figure 8	[2]								
	delay	V _{CC} = 2 V		-	52	160	-	200	-	240	ns
		V _{CC} = 4.5 V		-	19	32	-	40	-	48	ns
		V _{CC} = 6 V		-	15	27	-	34	-	41	ns
		STCP to Qn; see Figure 9	[2]								
		V _{CC} = 2 V		-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V		-	20	35	-	44	-	53	ns
		V _{CC} = 6 V		-	16	30	-	37	-	45	ns
t _{PHL}	HIGH	MR to Q7S; see Figure 11									
	to LOW propagation	V _{CC} = 2 V		-	47	175	-	220	-	265	ns
	delay	V _{CC} = 4.5 V		-	17	35	-	44	-	53	ns
		V _{CC} = 6 V		-	14	30	-	37	-	45	ns
t _{en}	enable time	OE to Qn; see Figure 12	[3]								
		V _{CC} = 2 V		-	47	150	-	190	-	225	ns
		V _{CC} = 4.5 V		-	17	30	-	38	-	45	ns
		V _{CC} = 6 V		-	14	26	-	33	-	38	ns
t _{dis}	disable time	OE to Qn; see Figure 12	[4]								
		V _{CC} = 2 V		-	41	150	-	190	-	225	ns
		V _{CC} = 4.5 V		-	15	30	-	38	-	45	ns
		V _{CC} = 6 V		-	12	27	-	33	-	38	ns
t _W	pulse width	SHCP HIGH or LOW; see <u>Figure 8</u>									
		V _{CC} = 2 V		75	17	-	95	-	110	-	ns
		V _{CC} = 4.5 V		15	6	-	19	-	22	-	ns
		V _{CC} = 6 V		13	5	-	16	-	19	-	ns
		STCP HIGH or LOW; see <u>Figure 9</u>									
		V _{CC} = 2 V		75	11	-	95	-	110	-	ns
		V _{CC} = 4.5 V		15	4	-	19	-	22	-	ns
		V _{CC} = 6 V		13	3	-	16	-	19	-	ns
		MR LOW; see Figure 11									

74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Symbol	Parameter	rameter Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Мах	
		$V_{CC} = 2 V$	75	17	-	95	-	110	-	ns
		V _{CC} = 4.5 V	15	6	-	19	-	22	-	ns
		V _{CC} = 6 V	13	5	-	16	-	19	-	ns
t _{su}	set-up time	DS to SHCP; see Figure 10								
		V _{CC} = 2 V	50	11	-	65	-	75	-	ns
		V _{CC} = 4.5 V	10	4	-	13	-	15	-	ns
		V _{CC} = 6 V	9	3	-	11	-	13	-	ns
		SHCP to STCP; see <u>Figure 10</u>								
		V _{CC} = 2 V	75	22	-	95	-	110	-	ns
		V _{CC} = 4.5 V	15	8	-	19	-	22	-	ns
		V _{CC} = 6 V	13	7	-	16	-	19	-	ns
t _h	hold time	DS to SHCP; see Figure 10								
		$V_{CC} = 2 V$	3	-6	-	3	-	3	-	ns
		V _{CC} = 4.5 V	3	-2	-	3	-	3	-	ns
		V _{CC} = 6 V	3	-2	-	3	-	3	-	ns
t _{rec}	recovery	MR to SHCP; see Figure 11								
	time	$V_{CC} = 2 V$	50	-19	-	65	-	75	-	ns
		V _{CC} = 4.5 V	10	-7	-	13	-	15	-	ns
		V _{CC} = 6 V	9	-6	-	11	-	13	-	ns
f _{max}	maximum frequency	SHCP or STCP; see <u>Figure 8</u> and <u>Figure 9</u>								
		V _{CC} = 2 V	9	30	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	91	-	24	-	20	-	MHz
		V _{CC} = 6 V	35	108	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{\text{CC}}$ ^{[5] [6]}	-	115	-	-	-	-	-	pF
74HCT59	5; V _{CC} = 4.5 V	/ to 5.5 V				1			1	
t _{pd}	propagation	SHCP to Q7S; see Figure 8 ^[2]	-	25	42	-	53	-	63	ns
	delay	STCP to Qn; see Figure 9 ^[2]	-	24	40	-	50	-	60	ns
t _{PHL}	HIGH to LOW propagation delay	MR to Q7S; see <u>Figure 11</u>	-	23	40	-	50	-	60	ns
t _{en}	enable time	OE to Qn; see Figure 12 ^[3]	-	21	35	-	44	-	53	ns
t _{dis}	disable time	OE to Qn; see Figure 12 [4]	-	18	30	-	38	-	45	ns

74HC_HCT595

Product data sheet

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74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Symbol	Parameter	Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
				Min	Тур ^[1]	Мах	Min	Мах	Min	Max	
t _{vv}	pulse width	SHCP HIGH or LOW; see <u>Figure 8</u>		16	6	-	20	-	24	-	ns
		STCP HIGH or LOW; see <u>Figure 9</u>		16	5	-	20	-	24	-	ns
		MR LOW; see Figure 11		20	8	-	25	-	30	-	ns
t _{su}	set-up time	DS to SHCP; see Figure 9		16	5	-	20	-	24	-	ns
		SHCP to STCP; see <u>Figure 9</u>		16	8	-	20	-	24	-	ns
t _h	hold time	DS to SHCP; see Figure 10		3	-2	-	3	-	3	-	ns
t _{rec}	recovery time	MR to SHCP; see Figure 11		10	-7	-	13	-	15	-	ns
f _{max}	maximum frequency	SHCP and STCP; see <u>Figure 8</u> and <u>Figure 9</u>		30	52	-	24	-	20	-	MHz
C _{PD}	power dissipation capacitance	f_i = 1 MHz; V _I = GND to V _{CC} - 1.5 V	[5] [6]	-	130	-	-	-	-	-	pF

Typical values are measured at nominal supply voltage. [1]

[2] [3] t_{pd} is the same as t_{PHL} and t_{PLH} .

 t_{en} is the same as t_{PZL} and t_{PZH} . [4] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

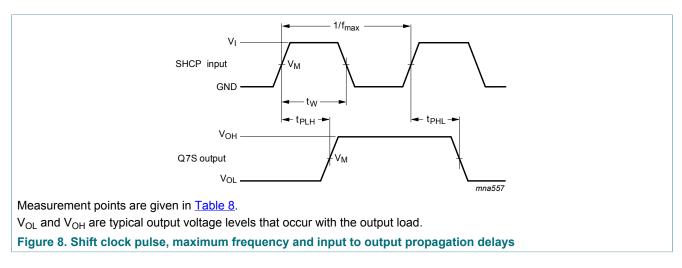
 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs;

 C_1 = output load capacitance in pF;

 V_{CC} = supply voltage in V. All 9 outputs switching.

[6]

11.1 Waveforms and test circuit



74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

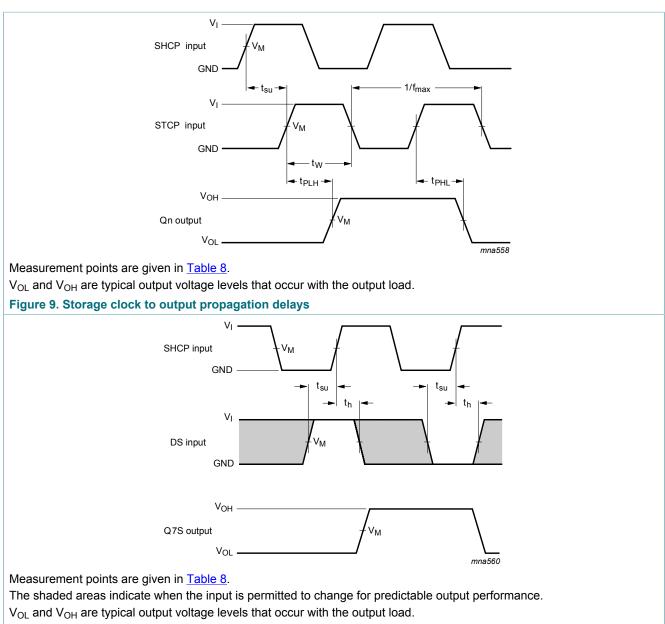


Figure 10. Data set-up and hold times

74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

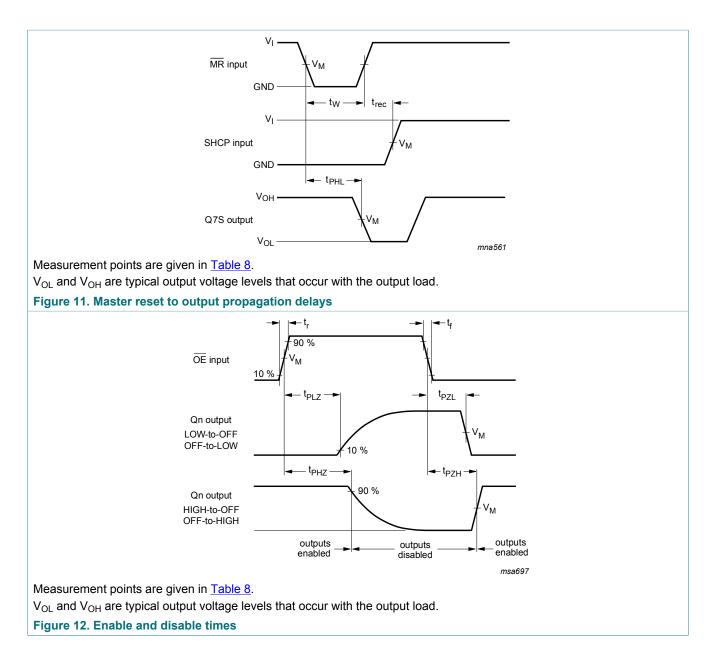


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC595	0.5V _{CC}	0.5V _{CC}
74HCT595	1.3 V	1.3 V

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74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

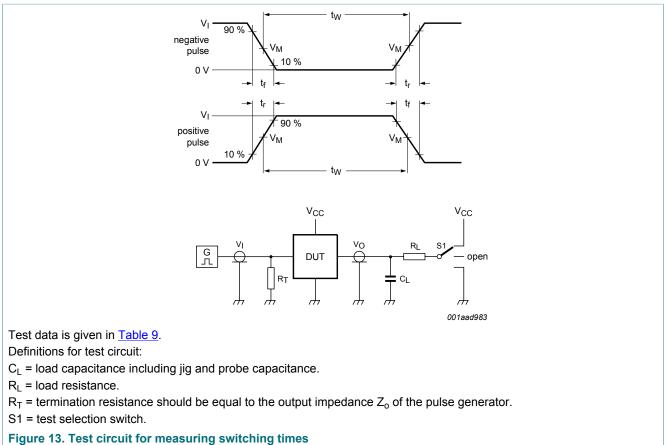


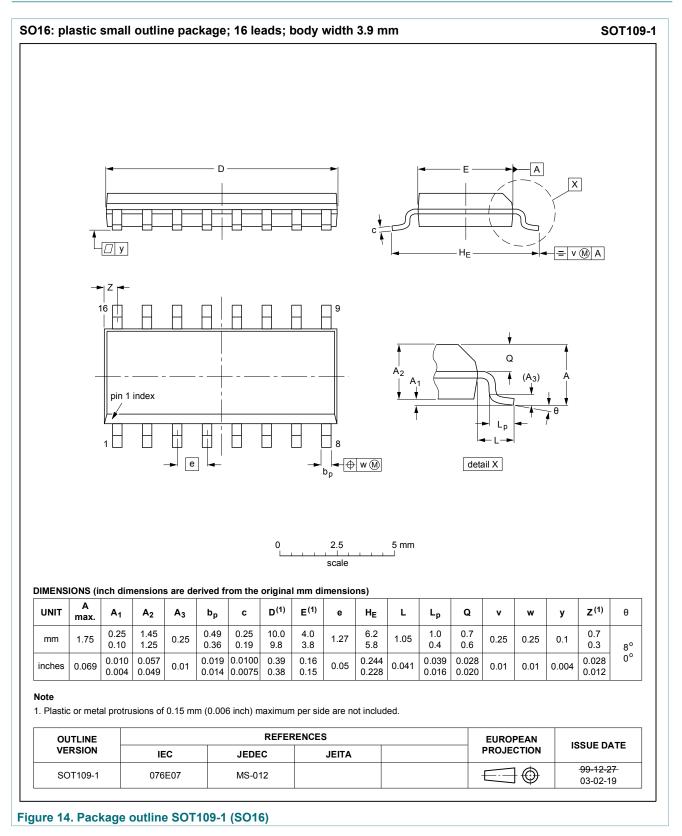
Figure 13. Test circuit for measuring switching tim

Table 9. Test data

Туре	Input	·	Load		S1 position			
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74HC595	V _{CC}	6 ns	50 pF	1 kΩ	open	GND	V _{CC}	
74HCT595	3 V	6 ns	50 pF	1 kΩ	open	GND	V _{CC}	

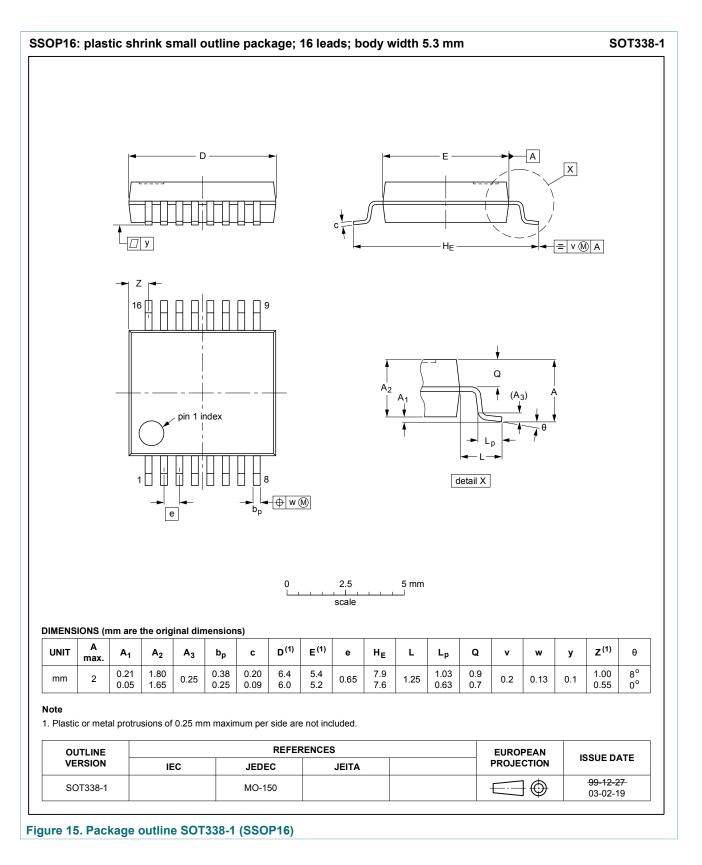
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12 Package outline



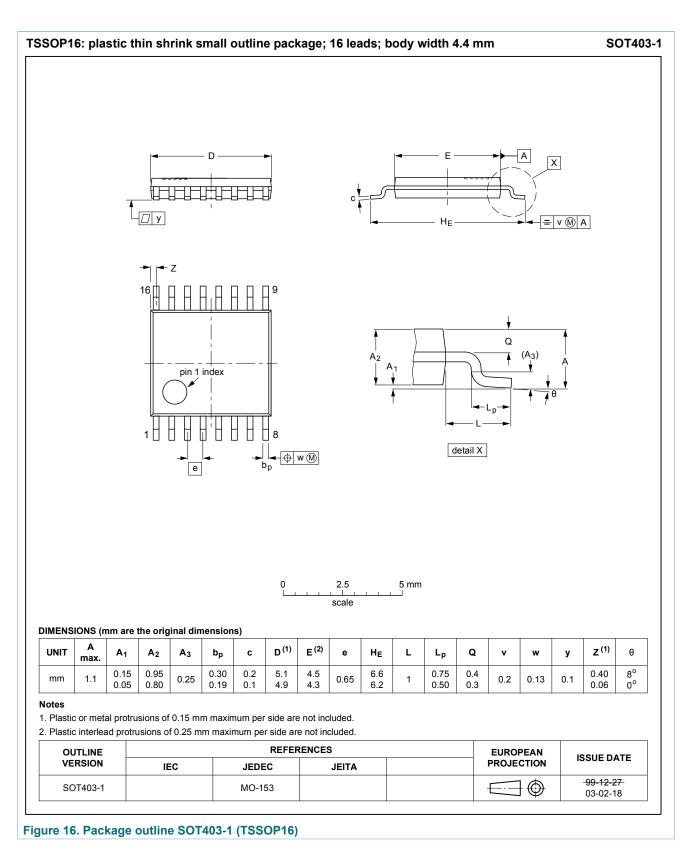
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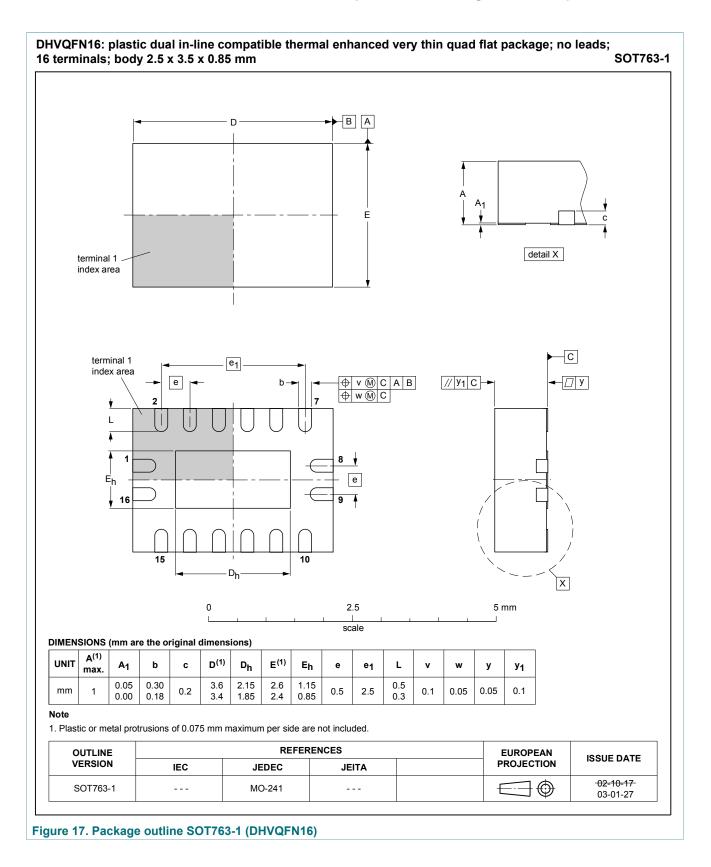
74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state



74HC_HCT595 Product data sheet

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state



74HC_HCT595 Product data sheet

13 Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

14 Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT595 v.9	20170228	Product data sheet	-	74HC_HCT595 v.8		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 					
74HC_HCT595 v.8	20160225	Product data sheet	-	74HC_HCT595 v.7		
Modifications:	Type numbers 74HC595N and 74HCT595N (SOT38-4) removed.					
74HC_HCT595 v.7	20150126	Product data sheet	-	74HC_HCT595 v.6		
Modifications:	• Table 7: Power dissipation capacitance condition for 74HCT595 is corrected.					
74HC_HCT595 v.6	20111212	Product data sheet	-	74HC_HCT595 v.5		
Modifications:	Legal pages updated.					
74HC_HCT595 v.5	20110628	Product data sheet	-	74HC_HCT595 v.4		
74HC_HCT595 v.4	20030604	Product specification	-	74HC_HCT595_CNV v.3		
74HC_HCT595_CNV v.3	19980604	Product specification	-	-		

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

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74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Ordering information	2
5	Functional diagram	2
6	Pinning information	4
6.1	Pinning	4
6.2	Pin description	4
7	Functional description	5
8	Limiting values	6
9	Recommended operating conditions	6
10	Static characteristics	7
11	Dynamic characteristics	9
11.1	Waveforms and test circuit	11
12	Package outline	15
13	Abbreviations	19
14	Revision history	19
15	Legal information	20

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